

GP1SQ50/GP1SQ51V High Reliability Photointerrupter

GP1SQ52/GP1SQ53

■ Features

1. High reliability

Temperature cycling test : 80% or more of lower specification limit after 100 cycling

Conditions :

- 40°C (30 minutes) to +25°C (5 minutes)
- to 100°C (30 minutes) to +25°C (5 minutes)

2. Both-sides mounting type **GP1SQ50** (Gap: 3mm, slit width: 0.5mm)

One-side mounting type **GP1SQ51V** (Gap: 3mm, slit width: 0.5mm)

PWB direct mounting type **GP1SQ52** (Gap: 3mm, slit width: 0.5mm)

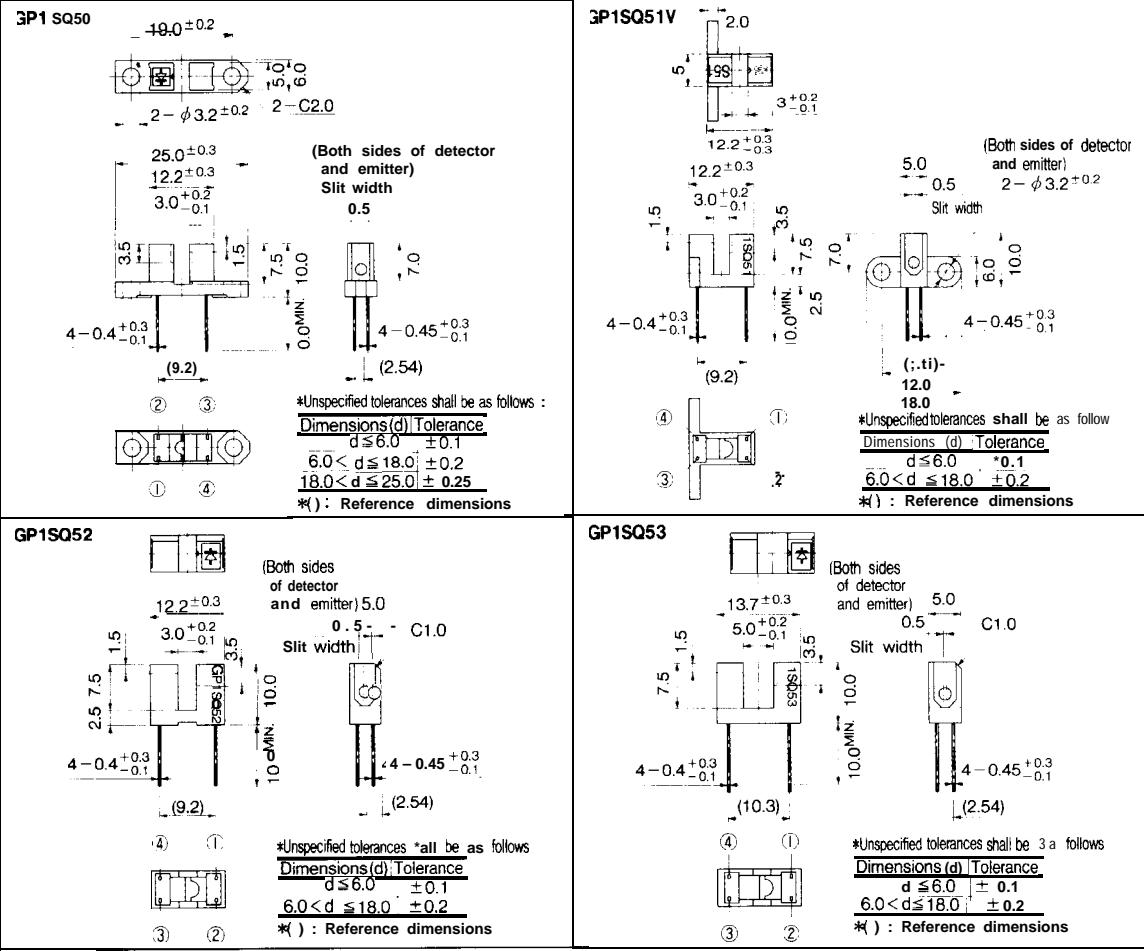
GP1SQ53 (Gap: 5mm, slit width: 0.5mm)

1. Oil fan heaters

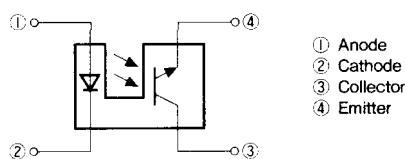
2. Automatic vending machines

■ Outline Dimensions

(Unit : mm)



Internal connection diagram (Common to 4 models)

**Absolute Maximum Ratings**

(Ta = 25°C)

Parameter		Symbol	Rating	Unit
Input	Forward current	I _F	50	mA
	*1 Peak forward current	I _{FM}	1	A
	Reverse voltage	V _R	6	v
	power dissipation	P	75	mW
output	Collector -emitter voltage	V _{CEO}	35	v
	Emitter-collector voltage	V _{ECO}	6	v
	Collector current	I _C	20	mA
	Collector power dissipation	P _C	75	mW
Operating power temperature		T _{opr}	-30 to +85	°C
Storage temperature		T _{stg}	-40 to +100	°C
*2 Soldering temperature		T _{sol}	260	°C

*1 Pulse width ≤ 100 μs, Duty ratio = 0.01

*2 For 5 seconds

Electro-optical Characteristics

(Ta = 25°C)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input	Forward voltage	V _F	I _F = 20mA	·	1.25	1.4	v
	Peak forward voltage	V _{FM}	I _{FM} = 0.5A	—	3	4	v
	Reverse current	I _R	V _R = 3V	—	—	10	μA
output	Collector dark current	I _{CEO}	V _{CE} = 20V	—	1	100	nA
Transfer characteristics	Current transfer ratio	CTR	V _{CE} = 5V, I _F = 20mA	2.5	—	50	%
	Collector-emitter saturation voltage	V _{CE(sat)}	I _F = 40mA, *3I _C = 0.5mA	—	—	0.4	v
	Response time	t _r	V _{CE} = 2V, I _C = 2mA	—	3	15	μs
		t _f	R _L = 100 Ω	—	4	20	μs

*3 I_C = 0.2mA (GP1SQ53)

Fig. 1 Forward Current vs. Ambient Temperature

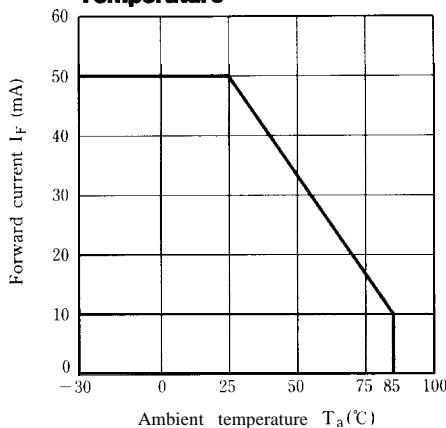


Fig. 3 Peak Forward Current vs. Duty Ratio

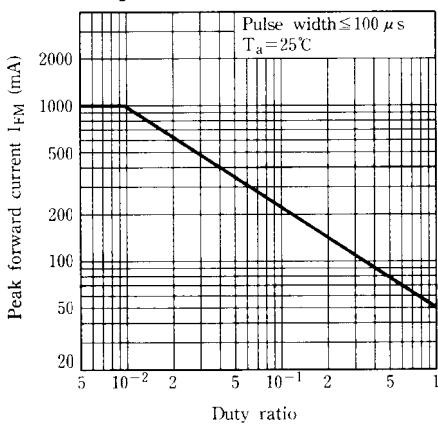


Fig. 5-a Collector Current vs. Forward Current (GP1SQ50/GP1SQ51V/GP1SQ52)

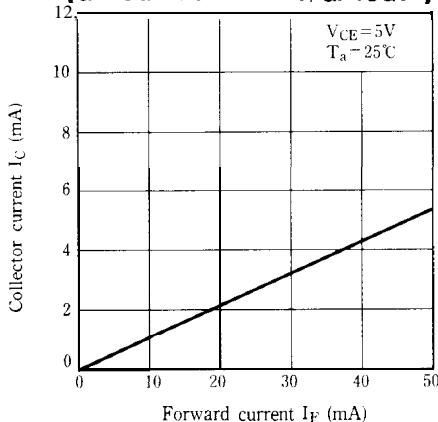


Fig. 2 Collector Power Dissipation vs. Ambient Temperature

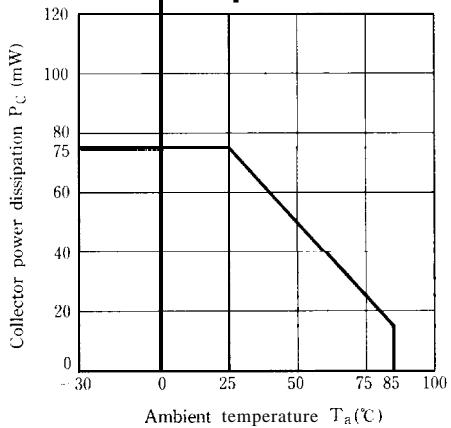


Fig. 4 Forward Current vs. Forward Voltage

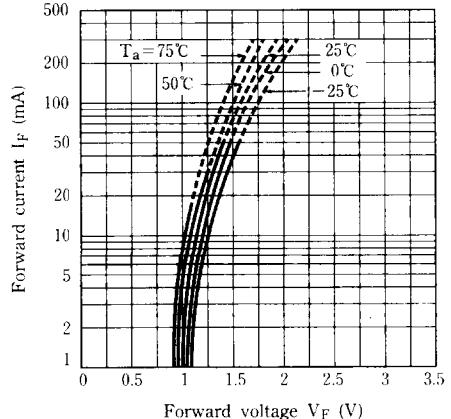


Fig. 5-b Collector Current vs. Forward Current (GP1SQ53)

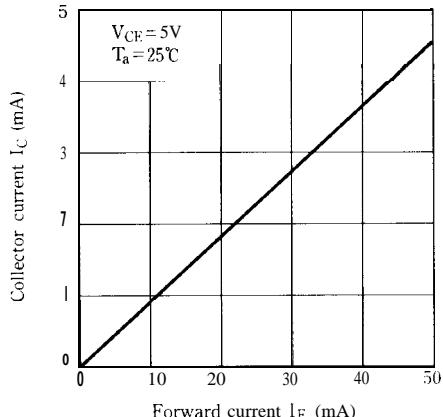


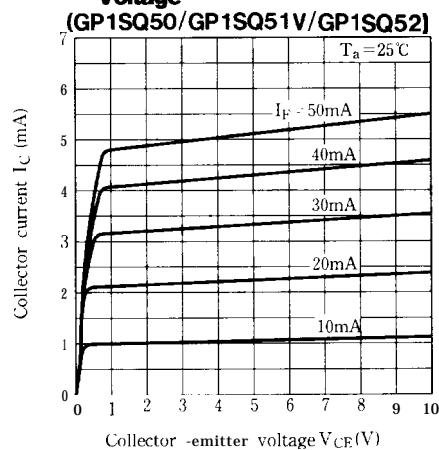
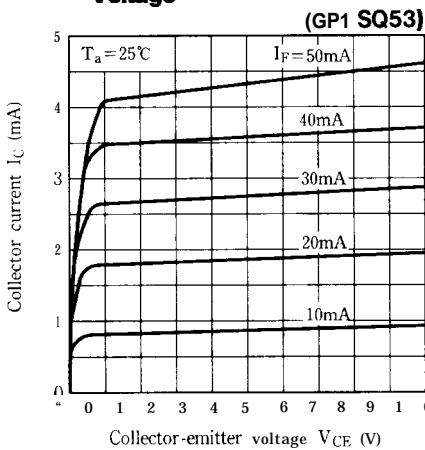
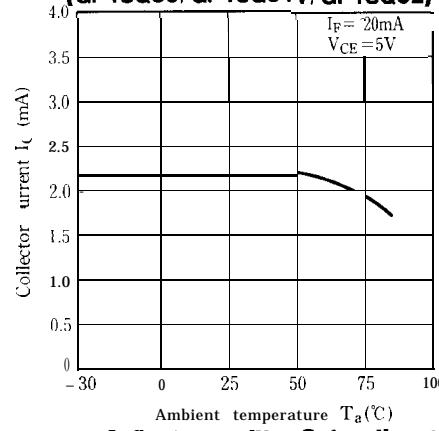
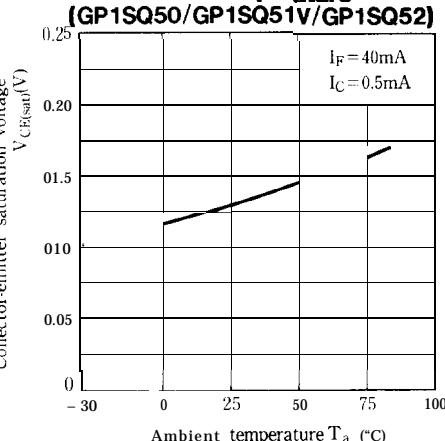
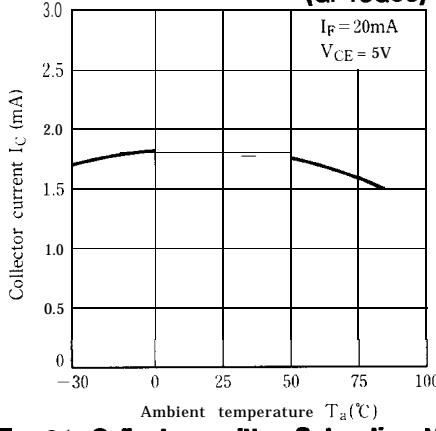
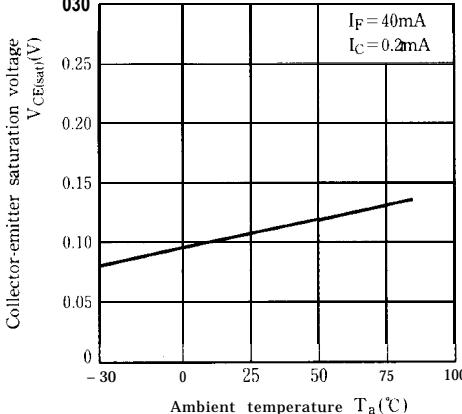
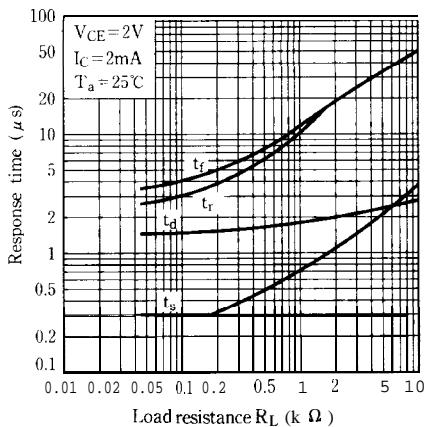
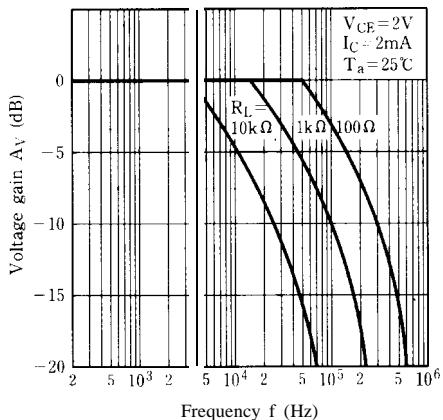
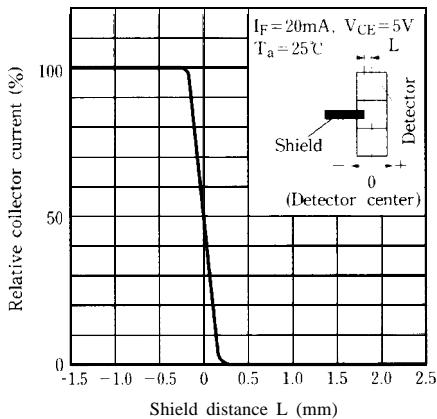
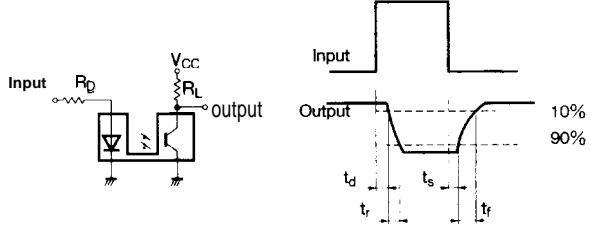
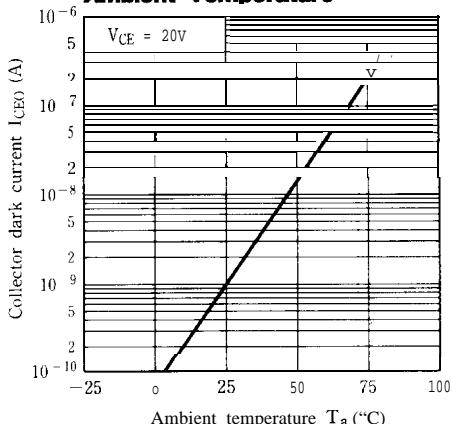
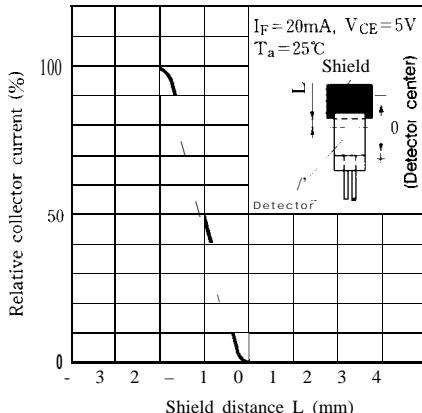
Fig. 6-a Collector Current vs. Collector-emitter Voltage**Fig. 6-b Collector Current vs. Collector-emitter Voltage****Fig. 7-a Collector Current vs. Ambient Temperature****Fig. 7-b Collector Current vs. Ambient Temperature****Fig. 8-a Collector-emitter Saturation Voltage vs. Ambient Temperature****Fig. 8-b Collector-emitter Saturation Voltage vs. Ambient Temperature**

Fig. 9 Response Time vs. Load Resistance**Fig.10 Frequency Response****Fig.12 Relative Collector Current vs. Shield Distance (1)****Test Circuit for Response Time****Fig.11 Collector Dark Current vs. Ambient Temperature****Fig.13 Relative Collector Current vs. Shield Distance (2)**

- Please refer to the chapter "Precautions for Use." (Page 78 to 93)